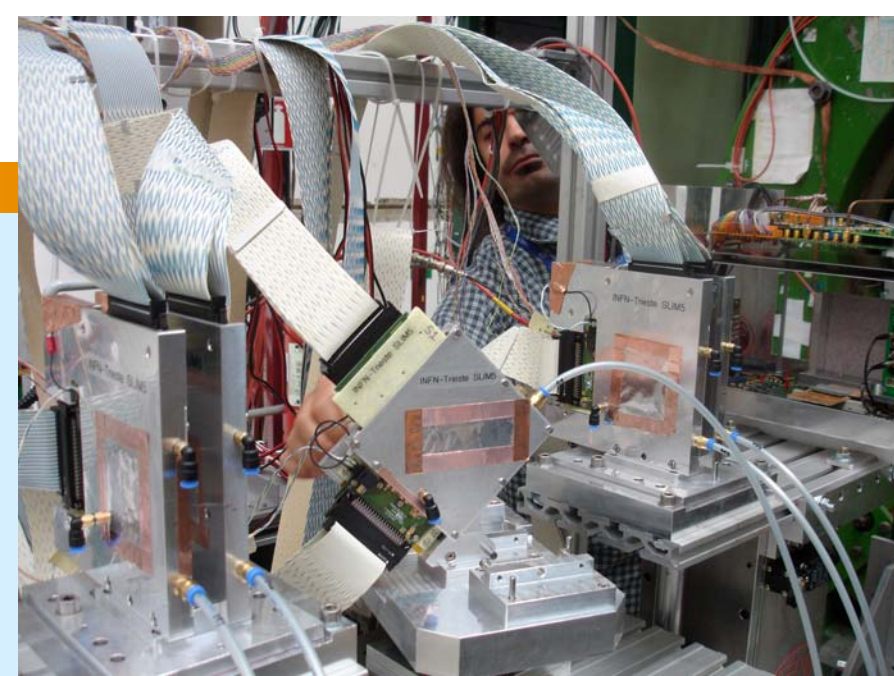


SLIM5 Beam Test Results for Thin Striplet Detector and Fast Readout Beam Telescope



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Abstract

In September 2008 the **SLIM5** collaboration submitted a low material budget silicon demonstrator to test with 12 GeV/c protons, at the PS-T9 **test-beam** at CERN. Two different detectors were placed as DUTs inside an high-resolution and fast-readout beam telescope.

The first DUT was a high resistivity double sided silicon detector, with short strips ("**striplets**") at 45° angle to the detector's edge, readout by the data-driven FSSR2 chip.

The other one was a 4k-Pixel Matrix of Deep N Well **MAPS**, developed in a 130 nm CMOS Technology, providing digital sparsified readout.

In the following I present the **striplets** and also the beam **telescope** characteristics, with some details about the frontend readout (based on the FSSR2 chip) and some preliminary results. A paper is in preparation.

SLIM5 project

Silicon detectors with **Low** Interactions with **Material** by INFN group **5** & eight Italian Universities

Aim

The SLIM5 was a project aiming to develop highly-segmented silicon tracking detectors, with low material budget, fast readout and data-driven architecture, and self-triggering capability.

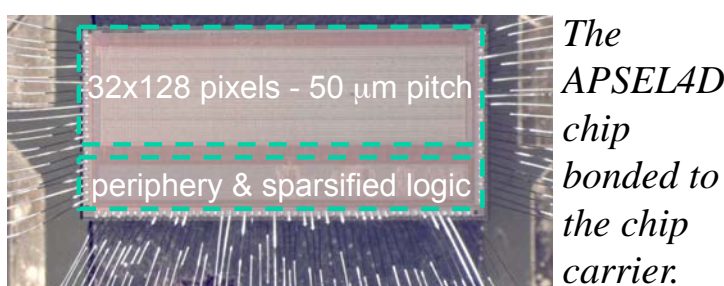
Detector options

The collaboration identified two detector options to reach this goal:

→ A new and challenging triple well CMOS Monolithic Active Pixel Sensor (**MAPS**) with in-pixel signal processing and sparsified capabilities.

Pixel cell is 50x50 μm^2 , active area close to 90% and 100-200 μm thick.

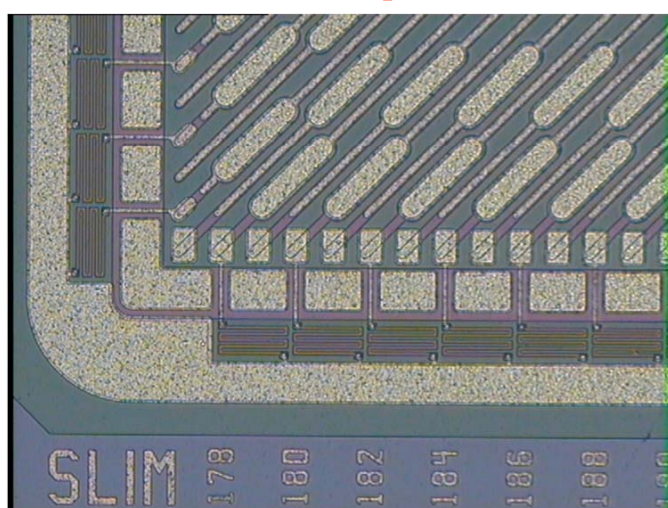
For more details, talk by M. Villa



→ A more traditional, but **thin** high resistivity double-sided silicon detector with short strips "**striplets**".

Strips are tilted by 45°, 50 μm pitch, active area 27 x 12.9 mm² and 200 μm thick. Strip cap. ~4 pF

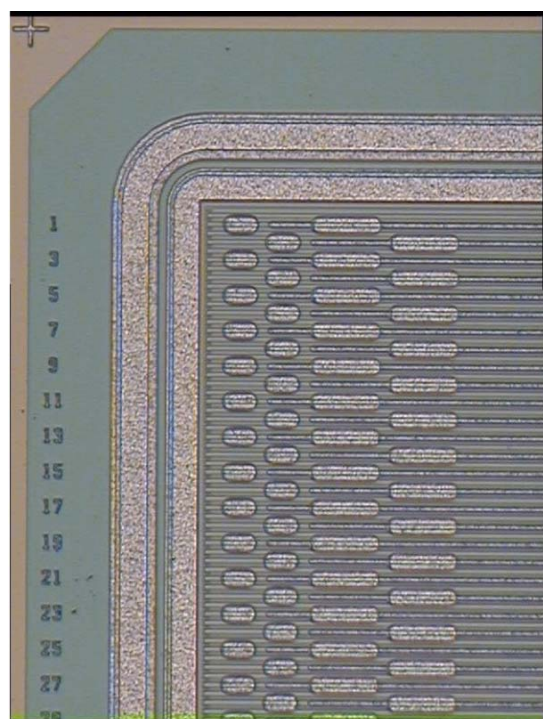
For more details, see Poster by I. Rashevskaya



Detail of a corner of the SLIM5 strip detector.

Telescope strip detectors

- 300 μm thick double-sided silicon strip detector with orthogonal strips
- 384 ch. read per side
- Area ~ 19 x 19 mm²
- 25 μm pitch on p-side with 50 μm readout
- 50 μm pitch on n-side
- Strip cap. 4.3 pF
- Fanout cap. 0.7±1.3 pF



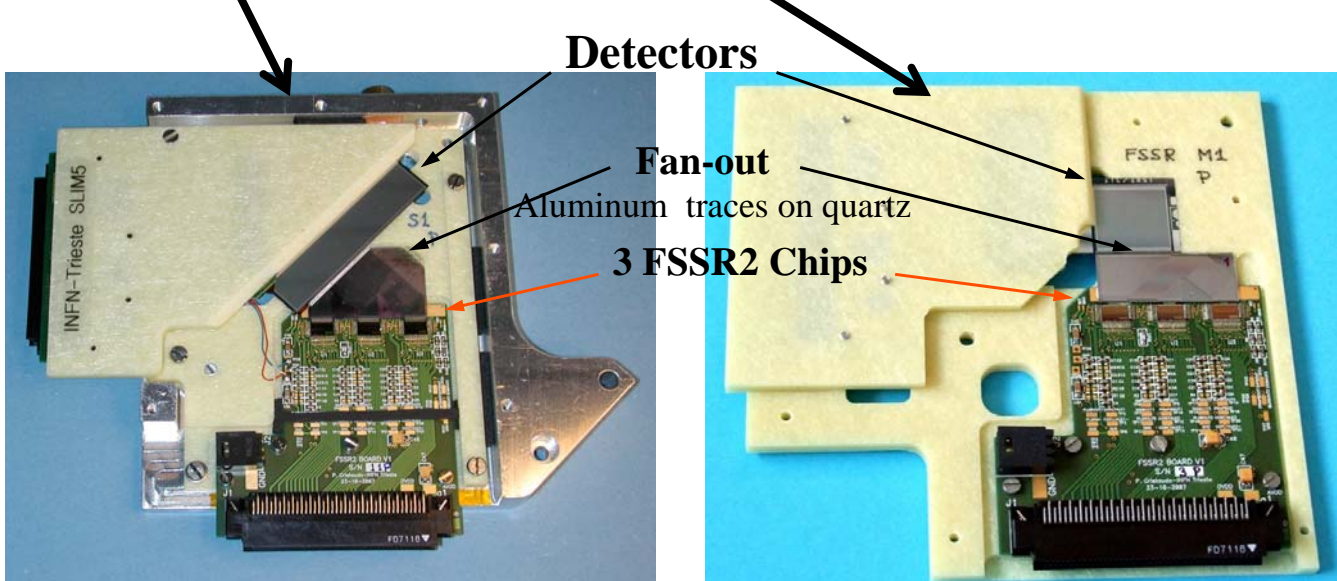
Detail of a corner of the SLIM5 telescope strip detector.

All devices provide directly timestamp info on hit.

Applications

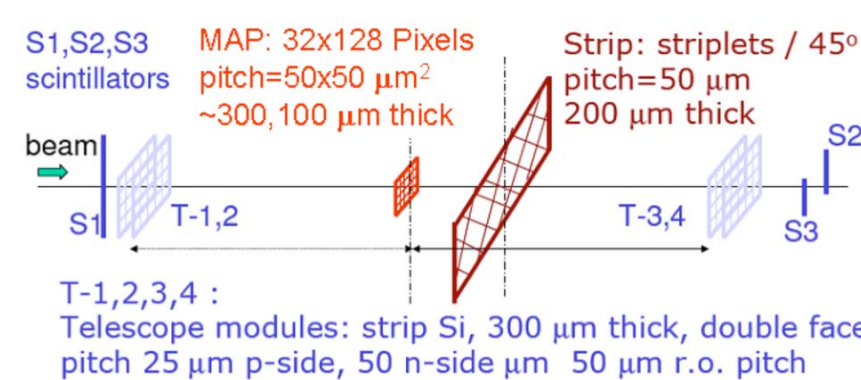
Such detectors can be used for the layer 0 in a future high-luminosity collider, such as the **Super B-factory** or the **International Linear Collider**.

Striplets and Telescope assembly



SLIM5 Beam test

3-16 Sep. 2008 @ PS-CERN with 12 GeV/c protons

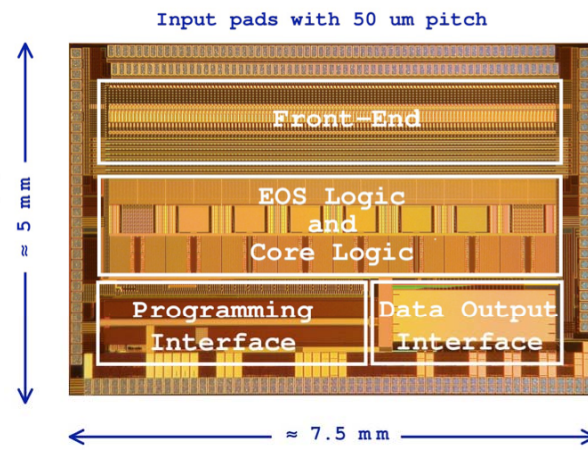


Schematic view of the SLIM5 beam test and picture of the experimental setup

Strip readout and Calibration Studies

Both the telescope strips and the striplets are readout by the second release of the Fermilab Silicon Strip Readout Chip (**FSSR2**), originally designed for the BTeV experiment.

- Completely data-driven
- Each chip serves 128 strips
- Only digital output providing:
 - address
 - time stamp
 - 3 bit amplitude
- Can be readout up to 70 MHz readout clock; Operated at 20 MHz, allowing a max data transmission rate of 240 Mbit/s over six lines.



A total of 384 channels were readout on each side of the sensor by three FSSR2 chips, here used for the first time to process also negative signals.

Among the several programmable options we have chosen to operate the chips at

- low gain, base line restorer selected,
- 125 ns shaping time,
- ~1/5 MIP threshold.

For **calibration** purposes, an internal square-wave pulser provides voltage steps on the integrated injection capacitance of 40 fF whose discharge feeds the amplification chain.

At fixed threshold, input amplitude was increased and fraction of pulses-over-threshold recorded. The result is fitted with an erf function, where σ is the estimated noise:

Detector	Polarity	Noise (ENC)	S/N	Threshold Dispersion	Gain (mV/fC)
Striplet	p	636	25	640	96
	n	1023	16	670	67
Telescope	p	502	48	640	97
	n	802	30	670	67

Data Analysis

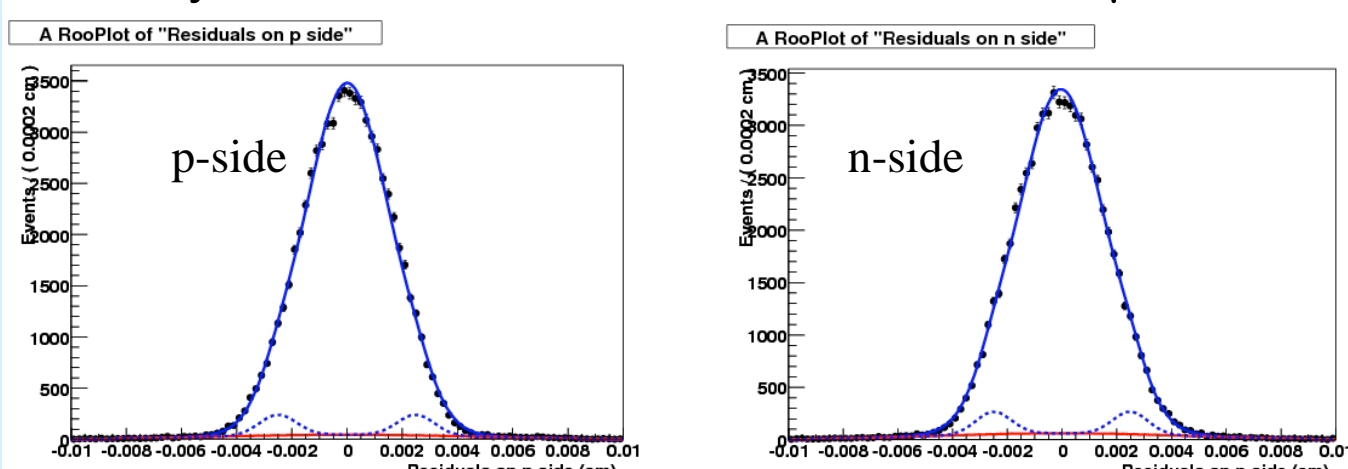
Pattern Recognition: Used a very simple algorithm : start from combining space point (p cluster + n cluster) on L0, L3 (outer telescope modules) to generate a pseudo track. Add space points on the inner telescope modules (L1, L2) if distance from pseudo track is within a fiducial road width, typically 0.1-0.2 cm before alignment and 0.05 cm after alignment.

Track fit: Least Square Method to extract track parameters. Multiple scattering not accounted in track fit. Prob(χ^2) is flat tuning errors for space points according to pitch, cluster size and pulse height.

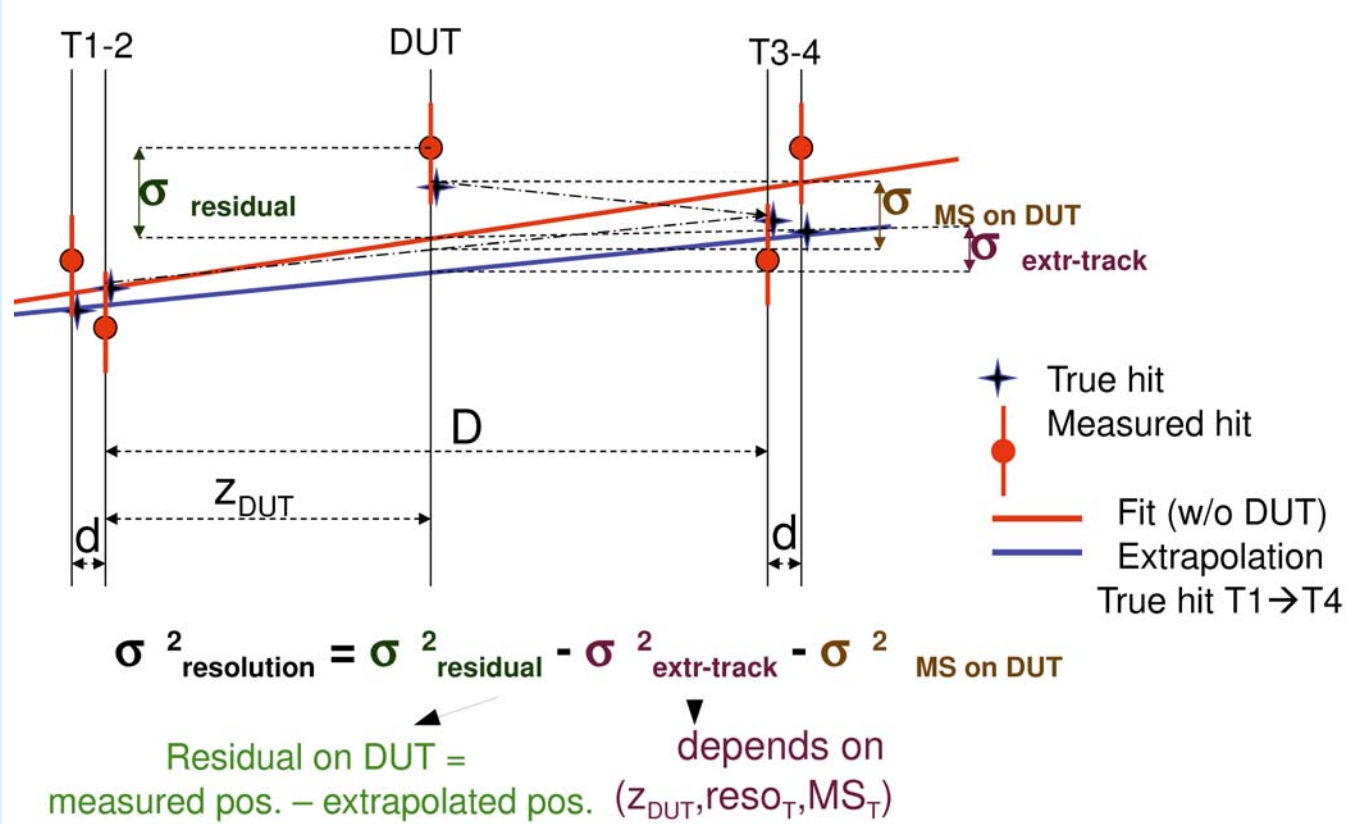
Alignment and DUT Residuals: select events with only one track passing from DUT active area, compute residual for DUT space points, perform iterative alignment minimizing residuals vs p,n translations and rotations.

Results

Besides the striplets, a **telescope** extra module was used as a DUT to evaluate resolution and efficiency. Cluster size is typically 1-2 in both cases. Residuals are fitted with narrow Gaussian + outlier Gaussian + two symmetrical Gaussians with mean $\pm 25\mu\text{m}$:



Resolution: the space point resolution is obtained from the fitted σ , after subtracting the 3.9 μm track error (1.75 and 5.3 μm for Telescope p and n side respectively) and the multiple scattering evaluated from MC: 6.0 (7.0) μm for 200 (300) μm of Si.



$\sigma^2_{\text{resolution}} = \sigma^2_{\text{residual}} - \sigma^2_{\text{extr-track}} - \sigma^2_{\text{MS on DUT}}$
Residual on DUT = measured pos. - extrapolated pos. ($z_{\text{DUT}}, \text{reso}_T, \text{MS}_T$) depends on

– 13.6 (7.2) μm for p side (pitch/ $\sqrt{12}$ = 14.2-7.2 μm)
– 14.1 (10.7) μm for n side (pitch/ $\sqrt{12}$ = 14.4 μm)

Efficiency 98.3±0.1 (99.4)%
Efficiency:= #Clusters>0/#tracks in a $\pm 80\mu\text{m}$ region

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